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Applicant: Leonard J. Olmer, et al

Art Unit: 1746

Serial No.: 10/675,575

Examiner: El Arini, Zeinab

Filed: 09/30/2003

Confirmation No.: 9967

Attorney Docket No.: Bevers 2-3-16-20/075903-81

For: In-Situ Removal of Surface Impurities Prior to Arsenic-Doped Polysilicon
Deposition in the Fabrication of a Heterojunction Bipolar TransistorCERTIFICATE OF FACSIMILE TRANSMISSION

June 7, 2006

VIA FACSIMILE TO 571-273-8300Mail Stop AF
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Alexandria, VA 22313-1450

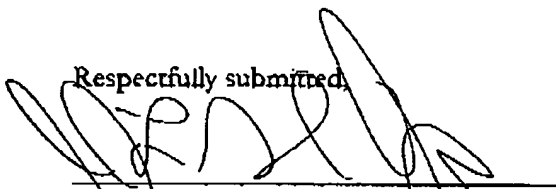
Dear Sir or Madam:

I hereby certify that the following papers (10 total pages) are being transmitted by facsimile transmission to the United States Patent and Trademark Office, fax number (571) 273-8300 on the date shown above:

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Amendment (9 pages)

Respectfully submitted,


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For: **In-Situ Removal of Surface Impurities Prior to Arsenic-Doped Polysilicon
Deposition in the Fabrication of a Heterojunction Bipolar Transistor****PROPOSED AMENDMENT UNDER 37 C.F.R. 116**

June 7, 2006

BY FACSIMILE TRANSMISSION TO 571-273-8300

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Alexandria, VA 22313-1450

Dear Sir or Madam:

In response to the final Office Action mailed on April 12, 2006, entry of the claim amendments set forth herein is respectfully requested under the provisions of 37 C.F.R. 116.